Signetics

74AC/ACT11640

Octal Transceiver w/Direction Pin; 3-State; INV

Product Specification

ACL Products

FEATURES

- **Octal bidirectional bus interface**
- **3-State buffers**
- **Inverting version of '245**
- **Output capability: ±24 mA**
- **CMOS (AC) and TTL (ACT) voltage level inputs**
- **50Ω incident wave switching**
- **Center-pin V_{CC} and ground configuration to minimize high-speed switching noise**
- **I_{CC} category: MSI**

DESCRIPTION

The 74AC/ACT11640 high-performance CMOS devices combine very high speed and high output drive comparable to the most advanced TTL families.

The 74AC/ACT11640 device is an octal transceiver featuring inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable ($\overline{OE}$) input for easy cascading and a Direction (DIR) input for direction control.

GENERAL INFORMATION

SYMBOL	PARAMETER	CONDITIONS T_A = 25°C; GND = 0V; V_{CC} = 5.0V		TYPICAL AC	TYPICAL ACT	UNIT
t_{PLH}/ t_{PHL}	Propagation delay A_n to B_n, or B_n to A_n	C_L = 50pF		4.9	6.0	ns
C_{PD}	Power dissipation capacitance per transceiver[1]	f = 1MHz; C_L = 50pF	Enabled	45	47	pF
			Disabled	12	12	
C_{IN}	Input capacitance	V_I = 0V or V_{CC}		4.0	4.0	pF
C_{IO}	I/O capacitance	$V_{I/O}$ = 0V or V_{CC}; Disabled		12	12	pF
I_{LATCH}	Latch-up current	Per Jedec JC40.2 Standard 17		500	500	mA

Note:

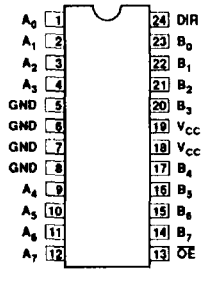
1. C_{PD} is used to determine the dynamic power dissipation (P_D in µW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_O)$ where:
   f_i = input frequency in MHz, C_L = output load capacitance in pF,
   f_O = output frequency in MHz, V_{CC} = supply voltage in V,
   $\Sigma (C_L \times V_{CC}^2 \times f_O)$ = sum of outputs

ORDERING INFORMATION

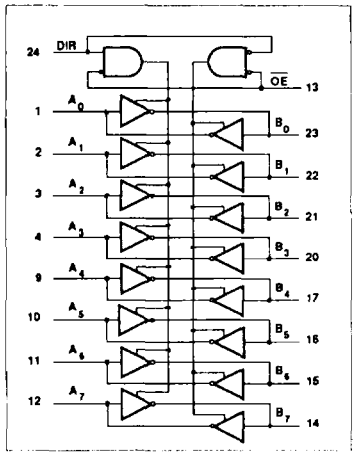
PACKAGES	TEMPERATURE RANGE	ORDER CODE
24-pin plastic DIP (300mil-wide)	-40°C to +85°C	74AC11640N 74ACT11640N
24-pin plastic SO (300mil-wide)	-40°C to +85°C	74AC11640D 74ACT11640D

PIN CONFIGURATION

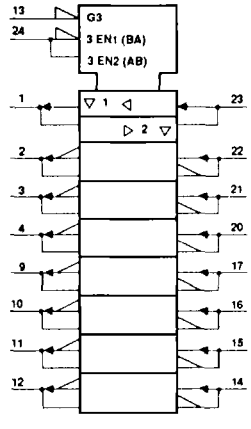
N and D Packages



LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
24	DIR	Direction control input
1, 2, 3, 4, 9, 10, 11, 12	A_0 - A_7	Data inputs/outputs (A side)
23, 22, 21, 20, 17, 16, 15, 14	B_0 - B_7	Data inputs/outputs (B side)
13	$\overline{OE}$	Output enable
5, 6, 7, 8	GND	Ground (0V)
18, 19	V_{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		INPUTS/OUTPUTS	
$\overline{OE}$	DIR	A_n	B_n
L	L	A = $\overline{B}$	inputs
L	H	inputs	B = $\overline{A}$
H	X	Z	Z

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	74AC11640			74ACT11640			UNIT
		Min	Nom	Max	Min	Nom	Max	
V_{CC}	DC supply voltage	3.0[1]	5.0	5.5	4.5	5.0	5.5	V
V_I	Input voltage	0		V_{CC}	0		V_{CC}	V
V_O	Output voltage	0		V_{CC}	0		V_{CC}	V
$\Delta t/\Delta v$	Input transition rise or fall rate	0		10	0		10	ns/V
T_A	Operating free-air temperature	-40		+85	-40		+85	°C

NOTE:

1. No electrical or switching characteristics are specified at V_{CC} < 3V. Operation between 2V and 3V is not recommended, but within that range, a device output will maintain a previously established logic state.

ABSOLUTE MAXIMUM RATINGS[1]

SYMBOL	PARAMETER	TEST CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to+7.0	V
I_{IK} or V_I	DC input diode current[2]	V_I < 0	-20	mA
		V_I > V_{CC}	20	
	DC input voltage		-0.5 to V_{CC} +0.5	V
I_{OK} or V_O	DC output diode current[2]	V_O < 0	-50	mA
		V_O > V_{CC}	50	
	DC output voltage		-0.5 to V_{CC} +0.5	V
I_O	DC output source or sink current per output pin	V_O = 0 to V_{CC}	±50	mA
I_{CC} or I_{GND}	DC V_{CC} current		±200	mA
	DC ground current		±200	
T_{STG}	Storage temperature		-65 to 150	°C
P_{TOT}	Power dissipation per package Plastic DIP	Above 70°C:derate linearly by 8mW/K	500	mW
	Power dissipation per package Plastic surface mount (SO)	Above 70°C:derate linearly by 6mW/K	400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		V_{CC}	74AC11640				74ACT11640				UNIT
					T_A = +25°C		T_A = -40°C to +85°C		T_A = +25°C		T_A = -40°C to +85°C		
				V	Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	High-level input voltage			3.0	2.10		2.10						V
				4.5	3.15		3.15		2.0		2.0		
				5.5	3.85		3.85		2.0		2.0		
V_{IL}	Low-level input voltage			3.0		0.90		0.90					V
				4.5		1.35		1.35		0.8		0.8	
				5.5		1.65		1.65		0.8		0.8	
V_{OH}	High-level output voltage	V_I = V_{IL} or V_{IH}	I_{OH} = -50μA	3.0	2.9		2.9						V
				4.5	4.4		4.4		4.4		4.4		
				5.5	5.4		5.4		5.4		5.4		
			I_{OH} = -4mA	3.0	2.58		2.48						
			I_{OH} = -24mA	4.5	3.94		3.8		3.94		3.8		
				5.5	4.94		4.8		4.94		4.8		
			I_{OH} = -75mA[1]	5.5			3.85				3.85		
V_{OL}	Low-level output voltage	V_I = V_{IL} or V_{IH}	I_{OL} = 50μA	3.0		0.1		0.1					V
				4.5		0.1		0.1		0.1		0.1	
				5.5		0.1		0.1		0.1		0.1	
			I_{OL} = 12mA	3.0		0.36		0.44					
			I_{OL} = 24mA	4.5		0.36		0.44		0.36		0.44	
				5.5		0.36		0.44		0.36		0.44	
			I_{OL} = 75mA[1]	5.5				1.65				1.65	
I_I	Input leakage current	V_I = V_{CC} or GND		5.5		±0.1		±1.0		±0.1		±1.0	μA
I_{OZ}	3-State output off-state current	V_I = V_{IL} or V_{IH}; V_O = V_{CC} or GND		5.5		±0.5		±5.0		±0.5		±5.0	μA
I_{CC}	Quiescent supply current	V_I = V_{CC} or GND, I_O = 0		5.5		8.0		80		8.0		80	μA
ΔI_{CC}	Supply current, TTL inputs High[2]	One input at 3.4V, other inputs at V_{CC} or GND		5.5						0.9		1.0	mA

NOTES:
1. Not more than one output should be tested at a time, and the duration of the test should not exceed 10ms.
2. This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0V or V_{CC}.

AC ELECTRICAL CHARACTERISTICS AT 3.3V ±0.3V

SYMBOL	PARAMETER	WAVEFORM	74AC11640					UNIT
			T_A = +25°C			T_A = -40°C to +85°C		
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation delay A_n to B_n, B_n to A_n	1	1.5 1.5	7.0 6.3	10.5 9.1	1.5 1.5	12.0 10.2	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1.5 1.5	8.9 8.4	12.5 12.9	1.5 1.5	14.3 14.6	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low level	2	1.5 1.5	7.9 8.6	10.0 11.0	1.5 1.5	10.8 12.0	ns

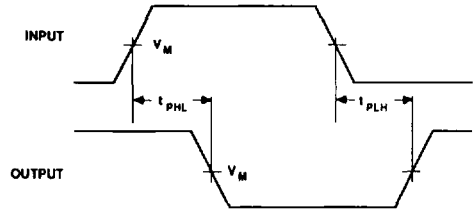
AC ELECTRICAL CHARACTERISTICS AT 5.0V ±0.5V

SYMBOL	PARAMETER	WAVEFORM	74AC11640					UNIT
			T_A = +25°C			T_A = -40°C to +85°C		
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation delay A_n to B_n, B_n to A_n	1	1.5 1.5	5.1 4.6	7.7 6.9	1.5 1.5	8.8 7.8	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1.5 1.5	6.5 6.1	9.4 9.4	1.5 1.5	10.6 10.6	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low level	2	1.5 1.5	6.7 7.2	8.6 9.1	1.5 1.5	9.3 9.9	ns

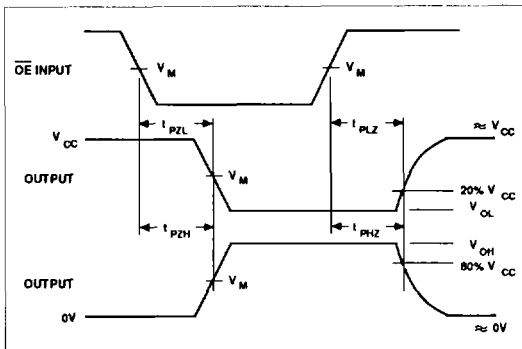
AC ELECTRICAL CHARACTERISTICS AT 5.0V ±0.5V

SYMBOL	PARAMETER	WAVEFORM	74ACT11640					UNIT
			T_A = +25°C			T_A = -40°C to +85°C		
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation delay A_n to B_n, B_n to A_n	1	1.5 1.5	6.3 5.7	9.6 8.6	1.5 1.5	10.5 9.5	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1.5 1.5	8.8 8.4	12.2 12.3	1.5 1.5	13.4 13.6	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low level	2	1.5 1.5	9.1 9.6	12.9 13.1	1.5 1.5	13.9 14.2	ns

AC WAVEFORMS



Waveform 1. Waveforms Showing the Input to Output Propagation Delays

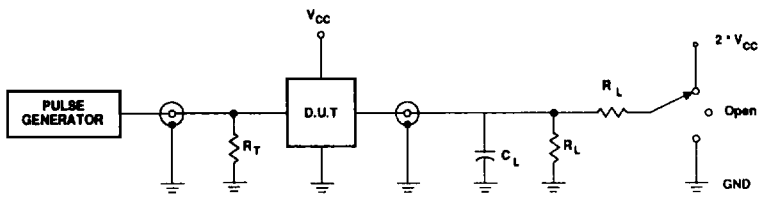


Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

WAVEFORM CONDITIONS

	INPUTS	OUTPUTS
AC	V_{IN} = GND to V_{CC}, V_M = 50% V_{CC}	V_{OUT} = V_{OL} to V_{OH}
ACT	V_{IN} = GND to 3.0V, V_M = 1.5V	V_M = 50% V_{CC}

TEST CIRCUIT



Test Circuit

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	2*VCC
t_{PHZ}/t_{PZH}	GND

SWITCH POSITION

DEFINITIONS

C_L = Load capacitance, 50pF; includes jig and probe capacitance

R_L = Load resistor, 500Ω

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators

Input pulses: PRR ≤ 10MHz

$t_r = t_f$ = 3ns